# High Speed Infrared Emitting Diode, 890 nm, GaAIAs Double Hetero 



## DESCRIPTION

TSHF5210 is an infrared, 890 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a clear, untinted plastic package.

## FEATURES

- Package type: leaded
- Package form: T-13/4
- Dimensions (in mm): $\varnothing 5$
- Leads with stand-off
- Peak wavelength: $\lambda_{p}=890 \mathrm{~nm}$
- High reliability COMPLANT
- High radiant power
- High radiant intensity (5-2008)**
- Angle of half intensity: $\varphi= \pm 10^{\circ}$
- Low forward voltage
- Suitable for high pulse current operation
- High modulation bandwidth: $\mathrm{f}_{\mathrm{c}}=12 \mathrm{MHz}$
- Good spectral matching with Si photodetectors
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
Note
** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902


## APPLICATIONS

- Infrared high speed remote control and free air data transmission systems with high modulation frequencies or high data transmission rate requirements
- Transmission systems according to IrDA requirements and for carrier frequency based systems (e.g. ASK/FSK coded, 450 kHz or 1.3 MHz )
- Smoke-automatic fire detectors

| PRODUCT SUMMARY |  |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: |
| COMPONENT | $\mathbf{I}_{\mathbf{e}}(\mathbf{m W} / \mathbf{s r})$ | $\varphi(\mathbf{d e g})$ | $\lambda_{\mathbf{p}}(\mathbf{n m})$ | $\mathbf{t}_{\mathbf{r}}(\mathbf{n s})$ |  |
| TSHF5210 | 180 | $\pm 10$ | 890 | 30 |  |

Note

- Test conditions see table "Basic Characteristics"


## ORDERING INFORMATION

| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM |
| :--- | :---: | :---: | :---: |
| TSHF5210 | Bulk | MOQ: $4000 \mathrm{pcs}, 4000 \mathrm{pcs} / \mathrm{bulk}$ | T-13/4 |

## Note

- MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified) |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| Reverse voltage |  | $\mathrm{V}_{\mathrm{R}}$ | 5 | V |
| Forward current |  | $\mathrm{I}_{\mathrm{F}}$ | 100 | mA |
| Peak forward current | $\mathrm{t}_{\mathrm{p}} / \mathrm{T}=0.5, \mathrm{t}_{\mathrm{p}}=100 \mu \mathrm{~s}$ | $\mathrm{I}_{\text {FM }}$ | 200 | mA |
| Surge forward current | $\mathrm{t}_{\mathrm{p}}=100 \mu \mathrm{~s}$ | $\mathrm{I}_{\text {FSM }}$ | 1.5 | A |
| Power dissipation |  | $\mathrm{P}_{\mathrm{V}}$ | 160 | mW |
| Junction temperature |  | $\mathrm{T}_{\mathrm{j}}$ | 100 | ${ }^{\circ} \mathrm{C}$ |
| Operating temperature range |  | $\mathrm{T}_{\text {amb }}$ | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature range |  | $\mathrm{T}_{\text {stg }}$ | -40 to +100 | ${ }^{\circ} \mathrm{C}$ |
| Soldering temperature | $\mathrm{t} \leq 5 \mathrm{~s}, 2 \mathrm{~mm}$ from case | $\mathrm{T}_{\text {sd }}$ | 260 | ${ }^{\circ} \mathrm{C}$ |
| Thermal resistance junction/ambient | J-STD-051, leads 7 mm , soldered on PCB | $\mathrm{R}_{\text {thJA }}$ | 230 | K/W |



Fig. 1 - Power Dissipation Limit vs. Ambient Temperature


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS $\left(T_{\text {amb }}=25^{\circ} \mathrm{C}\right.$, unless otherwise specified)

| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Forward voltage | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}, \mathrm{t}_{\mathrm{p}}=20 \mathrm{~ms}$ | $\mathrm{V}_{\mathrm{F}}$ |  | 1.4 | 1.6 | V |
|  | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~A}, \mathrm{t}_{\mathrm{p}}=100 \mu \mathrm{~s}$ | $\mathrm{V}_{\mathrm{F}}$ |  | 2.3 |  | V |
| Temperature coefficient of $\mathrm{V}_{\mathrm{F}}$ | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}$ | TK VFF |  | -1.8 |  | mV/K |
| Reverse current | $\mathrm{V}_{\mathrm{R}}=5 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{R}}$ |  |  | 10 | $\mu \mathrm{A}$ |
| Junction capacitance | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}, \mathrm{E}=0$ | $\mathrm{C}_{\mathrm{j}}$ |  | 125 |  | pF |
| Radiant intensity | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}, \mathrm{t}_{\mathrm{p}}=20 \mathrm{~ms}$ | $\mathrm{I}_{\mathrm{e}}$ | 120 | 180 | 360 | $\mathrm{mW} / \mathrm{sr}$ |
|  | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~A}, \mathrm{t}_{\mathrm{p}}=100 \mu \mathrm{~s}$ | $\mathrm{I}_{\mathrm{e}}$ |  | 1800 |  | $\mathrm{mW} / \mathrm{sr}$ |
| Radiant power | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}, \mathrm{t}_{\mathrm{p}}=20 \mathrm{~ms}$ | $\phi_{e}$ |  | 50 |  | mW |
| Temperature coefficient of $\phi_{e}$ | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ | TK $\phi_{\text {e }}$ |  | -0.35 |  | \%/K |
| Angle of half intensity |  | $\varphi$ |  | $\pm 10$ |  | deg |
| Peak wavelength | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ | $\lambda_{p}$ |  | 890 |  | nm |
| Spectral bandwidth | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ | $\Delta \lambda$ |  | 40 |  | nm |
| Temperature coefficient of $\lambda_{\mathrm{p}}$ | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ | TK $\lambda_{p}$ |  | 0.25 |  | $\mathrm{nm} / \mathrm{K}$ |
| Rise time | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ | $\mathrm{t}_{\mathrm{r}}$ |  | 30 |  | ns |
| Fall time | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ | $\mathrm{t}_{\mathrm{f}}$ |  | 30 |  | ns |
| Cut-off frequency | $\mathrm{I}_{\mathrm{DC}}=70 \mathrm{~mA}, \mathrm{I}_{\mathrm{AC}}=30 \mathrm{~mA} \mathrm{pp}$ | $\mathrm{f}_{\mathrm{c}}$ |  | 12 |  | MHz |
| Virtual source diameter |  | d |  | 3.7 |  | mm |

BASIC CHARACTERISTICS $\left(T_{\text {amb }}=25^{\circ} \mathrm{C}\right.$, unless otherwise specified)


Fig. 3 - Pulse Forward Current vs. Pulse Duration


Fig. 4 - Forward Current vs. Forward Voltage


Fig. 5 - Radiant Intensity vs. Forward Current


Fig. 6 - Radiant Power vs. Forward Current


Fig. 7 - Relative Radiant Power vs. Wavelength


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

## PACKAGE DIMENSIONS in millimeters



technical drawings according to DIN specifications
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